

FDMC6675BZ

June 2014

P-Channel PowerTrench[®] MOSFET -30 V, -20 A, 14.4 m Ω

Features

- Max $r_{DS(on)}$ = 14.4 m Ω at V_{GS} = -10 V, I_D = -9.5 A
- Max $r_{DS(on)}$ = 27.0 m Ω at V_{GS} = -4.5 V, I_D = -6.9 A
- HBM ESD protection level of 8 kV typical(note 3)
- Extended V_{GSS} range (-25 V) for battery applications
- High performance trench technology for extremely low r_{DS(on)}
- High power and current handling capability
- Termination is Lead-free and RoHS Compliant

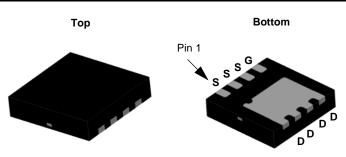
General Description

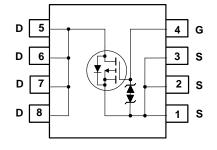
The FDMC6675BZ has been designed to minimize losses in load switch applications. Advancements in both silicon and package technologies have been combined to offer the lowest $r_{\text{DS(on)}}$ and ESD protection.

Application

- Load Switch in Notebook and Server
- Notebook Battery Pack Power Management







MLP 3.3x3.3

MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parai		Ratings	Units	
V_{DS}	Drain to Source Voltage			-30	V
V_{GS}	Gate to Source Voltage			±25	V
	Drain Current -Continuous	T _C = 25 °C		-20	
I_D	-Continuous	T _A = 25 °C	(Note 1a)	-9.5	Α
	-Pulsed			-32	
D	Power Dissipation	T _C = 25 °C		36	W
P_{D}	Power Dissipation	T _A = 25 °C	(Note 1a)	2.3	VV
T_J , T_{STG}	Operating and Storage Junction Tempe	rature Range		-55 to +150	°C

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance, Junction to Case	3.4	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient (Note 1a)	53	C/VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMC6675BZ	FDMC6675BZ	MLP 3.3X3.3	13 "	12 mm	3000 units

Electrical Characteristics $T_J = 25$ °C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	acteristics					
BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = -250 \mu A, V_{GS} = 0 V$	-30			V
$\frac{\Delta BV_{DSS}}{\Delta T_{J}}$	Breakdown Voltage Temperature Coefficient	I_D = -250 μ A, referenced to 25 °C		20		mV/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = -24 \text{ V},$ $V_{GS} = 0 \text{ V}$ $T_{J} = 125 \text{ °C}$			-1 -100	μА
I _{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 25 \text{ V}, V_{DS} = 0 \text{ V}$			±10	μΑ

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_D = -250 \mu A$	-1.0	-1.9	-3.0	V
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	I_D = -250 μA, referenced to 25 °C		-6		mV/°C
		$V_{GS} = -10 \text{ V}, I_D = -9.5 \text{ A}$		10.7	14.4	
r _{DS(on)}	r _{DS(on)} Static Drain to Source On Resistance	$V_{GS} = -4.5 \text{ V}, I_D = -6.9 \text{ A}$		17.4	27.0	mΩ
, ,		$V_{GS} = -10 \text{ V}, I_D = -9.5 \text{ A}, T_J = 125 \text{ °C}$		15.2	20.5	
9 _{FS}	Forward Transconductance	$V_{DD} = -5 \text{ V}, \ I_{D} = -9.5 \text{ A}$		28		S

Dynamic Characteristics

C _{iss}	Input Capacitance	V 45.V.V 0.V	2154	2865	pF
C _{oss}	Output Capacitance	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V},$ f = 1 MHz	392	525	рF
C _{rss}	Reverse Transfer Capacitance	1 = 1 1011 12	349	525	pF

Switching Characteristics

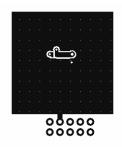
t _{d(on)}	Turn-On Delay Time		V_{DD} = -15 V, I_{D} = -9.5 A, V_{GS} = -10 V, R_{GEN} = 6 Ω		11	20	ns
t _r	Rise Time	V _{DD} = -15 V, I _D = -9			10	20	ns
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = -10 \text{ V}, R_{GEN}$			44	71	ns
t _f	Fall Time				26	42	ns
0	Total Gate Charge	$V_{GS} = 0 \text{ V to -10 V}$			46	65	nC
$Q_{g(TOT)}$	Total Gate Charge	$V_{GS} = 0 \text{ V to -5 V}$	$V_{DD} = -15 \text{ V},$		26	37	nC
Q_{gs}	Gate to Source Charge		I _D = -9.5 A		6.4		nC
Q_{gd}	Gate to Drain "Miller" Charge				13		nC

Drain-Source Diode Characteristics

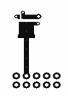
V _{SD} Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = -9.5 \text{ A}$ (Note 2)	0.89	1.3	V	
V SD	V _{SD} Source to Drain Diode Forward Voltage	$V_{GS} = 0 \text{ V}, I_{S} = -1.6 \text{ A}$ (Note 2)	0.73	1.2	V
t _{rr}	Reverse Recovery Time	I _F = -9.5 A, di/dt = 100 A/μs		24	38	ns
Q _{rr}	Reverse Recovery Charge			15	27	nC

NOTES

^{1.} R_{0JA} is determined with the device mounted on a 1 in² pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material. R_{0JC} is guaranteed by design while R_{0CA} is determined by the user's board design.



a. 53 °C/W when mounted on a 1 in² pad of 2 oz copper



b.125 °C/W when mounted on a minimum pad of 2 oz copper

- 2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0 %.
- 3. The diode connected between the gate and source servers only as protection against ESD. No gate overvoltage rating is implied.

Typical Characteristics T_J = 25 °C unless otherwise noted

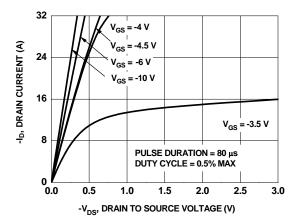


Figure 1. On Region Characteristics

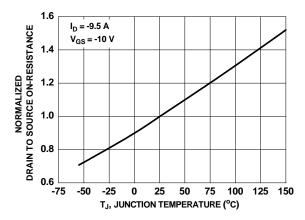


Figure 3. Normalized On Resistance vs Junction Temperature

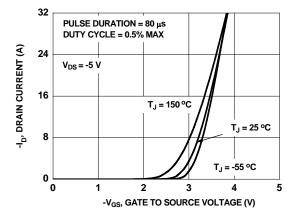


Figure 5. Transfer Characteristics

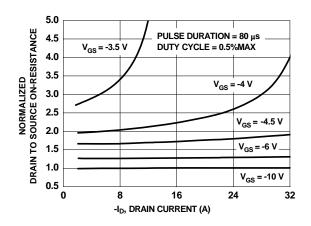


Figure 2. Normalized On-Resistance vs Drain Current and Gate Voltage

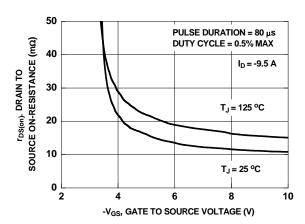


Figure 4. On-Resistance vs Gate to Source Voltage

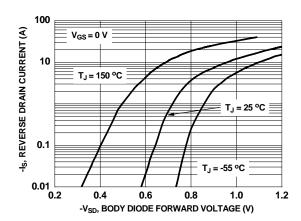


Figure 6. Source to Drain Diode Forward Voltage vs Source Current

Typical Characteristics $T_J = 25$ °C unless otherwise noted

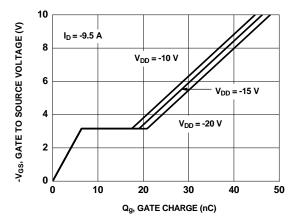


Figure 7. Gate Charge Characteristics

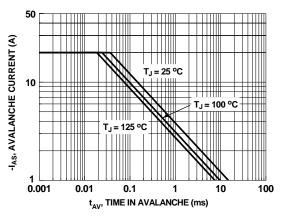


Figure 9. Unclamped Inductive Switching Capability

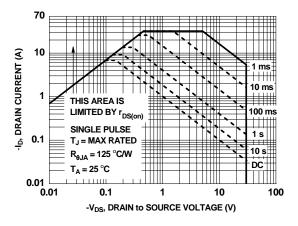


Figure 11. Forward Bias Safe Operating Area

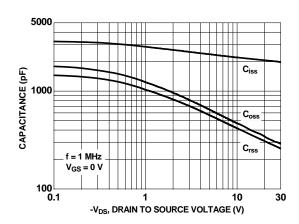


Figure 8. Capacitance vs Drain to Source Voltage

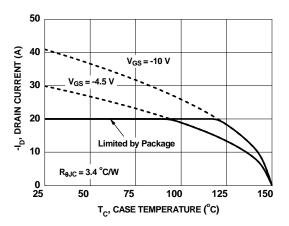


Figure 10. Maximum Continuous Drain Current vs Case Temperature

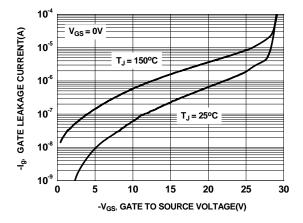


Figure 12. I_{qss} vs V_{qss}

Typical Characteristics $T_J = 25$ °C unless otherwise noted

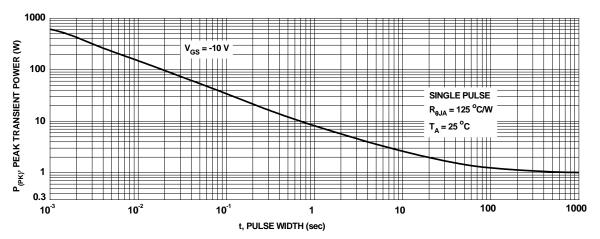


Figure 13. Single Pulse Maximum Power Dissipation

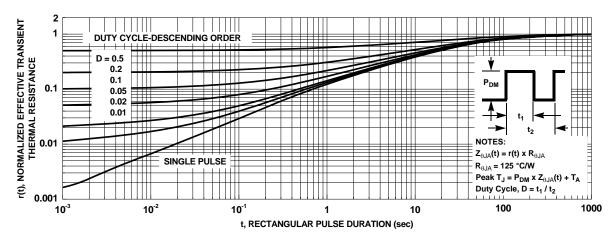
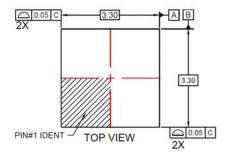
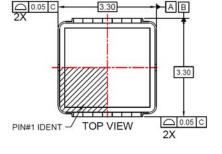
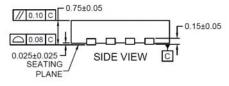


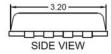
Figure 14. Junction-to-Ambient Transient Thermal Response Curve

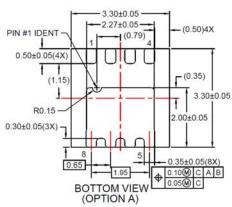
Dimensional Outline and Pad Layout

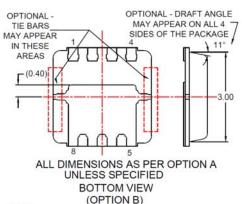








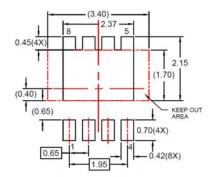




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- G. OPTION A SAWN MLP, OPTION B PUNCH MLP.





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